



# PSMN2R6-80YSF

NextPower 80 V, 2.7 mOhm, 218 A, N-channel MOSFET in LFAK56E package

27 April 2023

Objective data sheet

## 1. General description

NextPower 80 V, standard level gate drive MOSFET. Qualified to 175 °C and recommended for industrial and consumer applications.

## 2. Features and benefits

- Low  $Q_{rr}$  for higher efficiency and lower spiking
- 218 A  $I_{D(max)}$  – demonstrated continuous current rating
- Low  $Q_G \times R_{DS(on)}$  FOM for high efficiency switching applications
- Strong avalanche energy rating ( $E_{as}$ )
- Avalanche rated and 100% tested
- Ha-free and RoHS compliant LFAK56E package

## 3. Applications

- Synchronous rectifier in AC-DC and DC-DC
- Primary side switch in DC-DC
- BLDC motor control
- USB-PD adapters
- Full-bridge and half-bridge applications
- Flyback and resonant topologies

## 4. Quick reference data

Table 1. Quick reference data

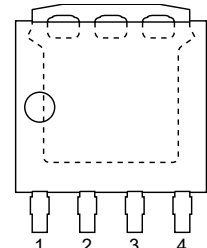
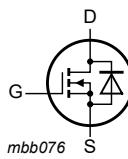
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$	-	-	80	V
$I_D$	drain current	$V_{GS} = 10\text{ V}; T_{mb} = 25\text{ °C}$	-	-	218	A
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ °C}; \text{Fig. 1}$	-	-	294	W
$T_j$	junction temperature		-55	-	175	°C
<b>Static characteristics</b>						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_j = 25\text{ °C}$	-	2.3	2.7	mΩ
		$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_j = 100\text{ °C}$	-	3.6	4.3	mΩ
<b>Dynamic characteristics</b>						
$Q_{GD}$	gate-drain charge	$I_D = 25\text{ A}; V_{DS} = 40\text{ V}; V_{GS} = 10\text{ V}$	[tbd]	15	[tbd]	nC
$Q_{G(tot)}$	total gate charge		[tbd]	83	[tbd]	nC
<b>Avalanche ruggedness</b>						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 58\text{ A}; V_{sup} \leq 80\text{ V}; R_{GS} = 50\text{ }\Omega;$ $V_{GS} = 10\text{ V}; T_{j(init)} = 25\text{ °C};$ unclamped; $t_p = 127\text{ }\mu\text{s}; \text{Fig. 2}$	[1]	-	382	mJ

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Source-drain diode</b>						
$Q_r$	recovered charge	$I_S = 25\text{ A}$ ; $di_S/dt = -100\text{ A}/\mu\text{s}$ ; $V_{GS} = 0\text{ V}$ ; $V_{DS} = 40\text{ V}$ ; <a href="#">Fig. 6</a>	-	27	-	nC

[1] Protected by 100% test

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 <p>LFAK56E; Power-SO8 (SOT1023)</p>	 <p>mbb076</p>
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN2R6-80YSF	LFAK56E; Power-SO8	plastic, single-ended surface-mounted package (LFAK56); 4 leads; 1.27 mm pitch	SOT1023

## 7. Limiting values

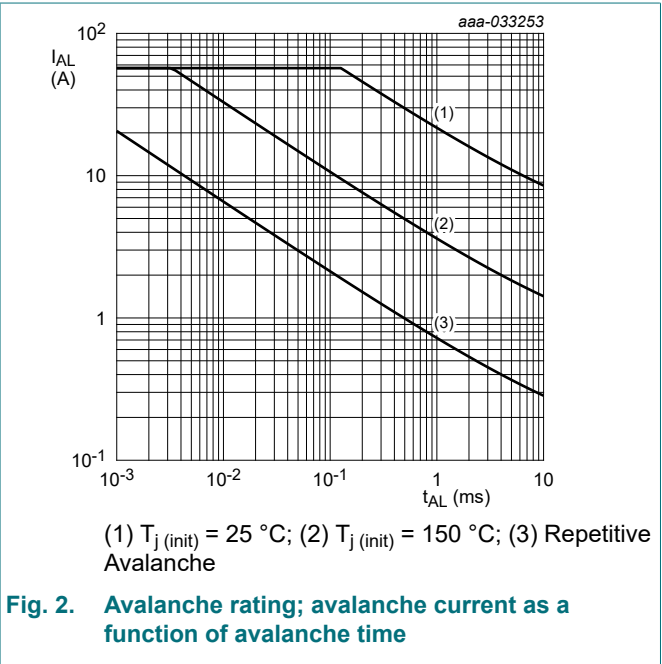
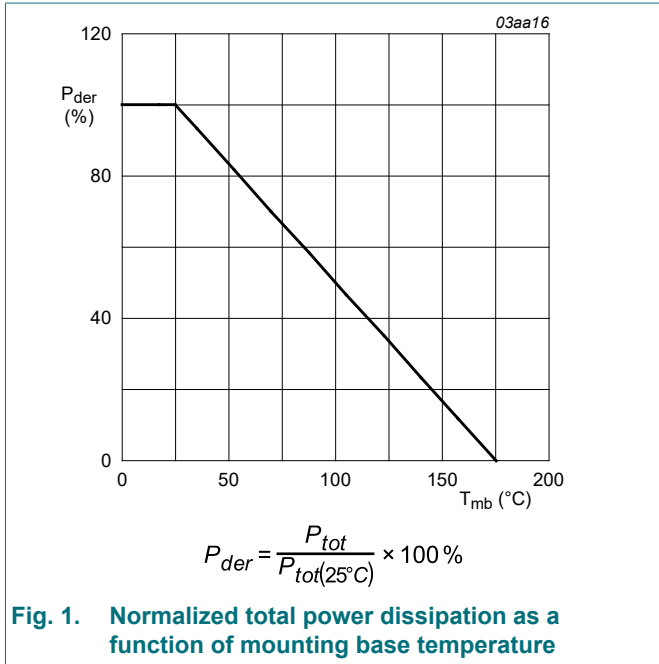
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).  $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise stated.

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ }^\circ\text{C} \leq T_j \leq 175\text{ }^\circ\text{C}$	-	80	V
$V_{DGR}$	drain-gate voltage	$25\text{ }^\circ\text{C} \leq T_j \leq 175\text{ }^\circ\text{C}$ ; $R_{GS} = 20\text{ k}\Omega$	-	80	V
$V_{GS}$	gate-source voltage		-20	20	V
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 1</a>	-	294	W
$I_D$	drain current	$V_{GS} = 10\text{ V}$ ; $T_{mb} = 25\text{ }^\circ\text{C}$	-	218	A
		$V_{GS} = 10\text{ V}$ ; $T_{mb} = 100\text{ }^\circ\text{C}$	-	154	A
$I_{DM}$	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ }^\circ\text{C}$	-	871	A
$T_{stg}$	storage temperature		-55	175	$^\circ\text{C}$
$T_j$	junction temperature		-55	175	$^\circ\text{C}$
$T_{sld(M)}$	peak soldering temperature		-	260	$^\circ\text{C}$
<b>Source-drain diode</b>					
$I_S$	source current	$T_{mb} = 25\text{ }^\circ\text{C}$	-	218	A
$I_{SM}$	peak source current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ }^\circ\text{C}$	-	871	A

Symbol	Parameter	Conditions	Min	Max	Unit	
<b>Avalanche ruggedness</b>						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 58 \text{ A}$ ; $V_{sup} \leq 80 \text{ V}$ ; $R_{GS} = 50 \Omega$ ; $V_{GS} = 10 \text{ V}$ ; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$ ; unclamped; $t_p = 127 \mu\text{s}$ ; <a href="#">Fig. 2</a>	[1]	-	382	mJ
$I_{AS}$	non-repetitive avalanche current	$V_{sup} \leq 80 \text{ V}$ ; $V_{GS} = 10 \text{ V}$ ; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$ ; $R_{GS} = 50 \Omega$ ; <a href="#">Fig. 2</a>	[1]	-	58	A

[1] Protected by 100% test



## 8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<a href="#">Fig. 3</a>	-	0.45	0.51	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	<a href="#">Fig. 4</a>	-	42	-	K/W
		<a href="#">Fig. 5</a>	-	85	-	K/W

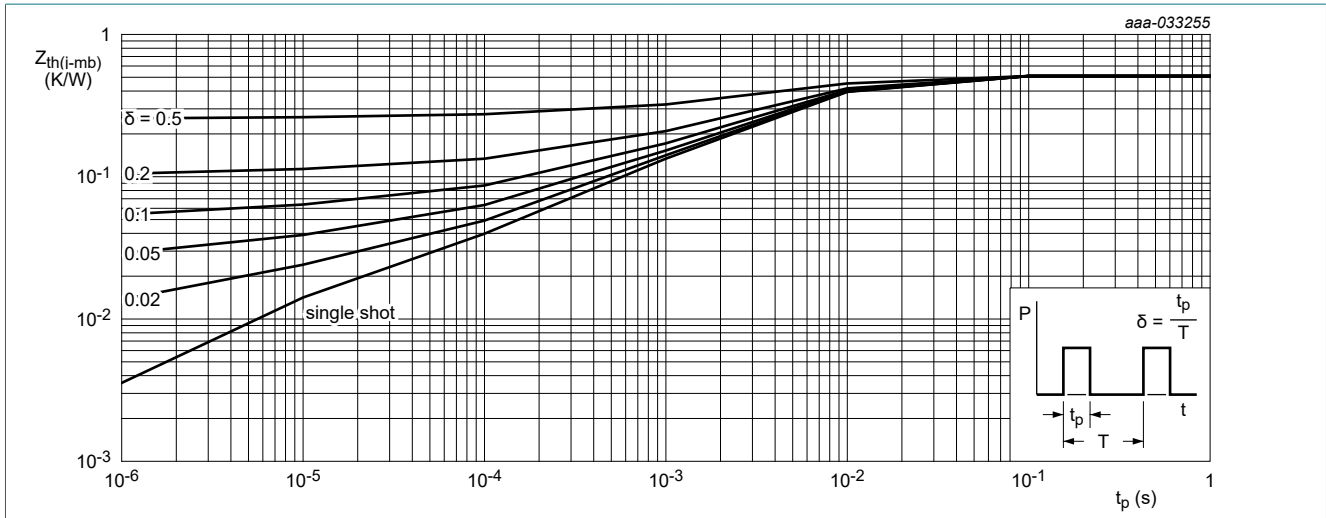


Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse duration

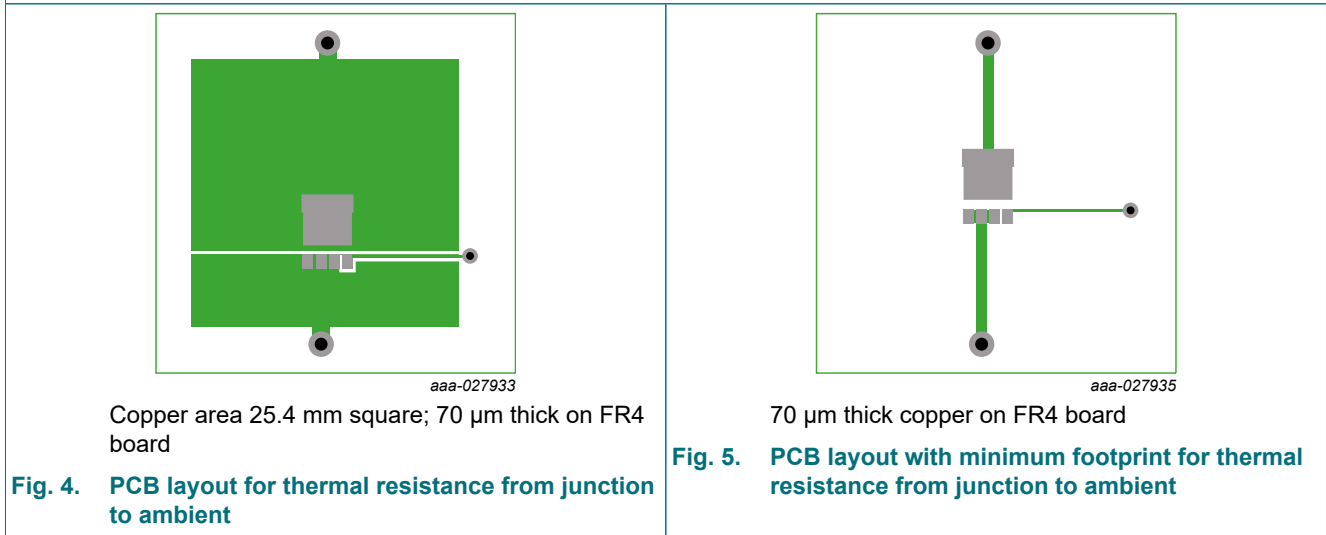


Fig. 4. PCB layout for thermal resistance from junction to ambient

Fig. 5. PCB layout with minimum footprint for thermal resistance from junction to ambient

## 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$	80	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$	72	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ }^\circ C$	2.2	3	3.8	V
		$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 175 \text{ }^\circ C$	-	1.8	-	V
		$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = -55 \text{ }^\circ C$	-	3.4	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	$25 \text{ }^\circ C \leq T_j \leq 150 \text{ }^\circ C$	-	-7.2	-	mV/K
$I_{DSS}$	drain leakage current	$V_{DS} = 80 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$	-	0.07	1	μA
		$V_{DS} = 80 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ }^\circ C$	-	2	100	μA
$I_{GSS}$	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$	-	2	100	nA
		$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$	-	2	100	nA

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_J = 25\text{ }^\circ\text{C}$	-	2.3	2.7	mΩ
		$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_J = 100\text{ }^\circ\text{C}$	-	3.6	4.3	mΩ
		$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_J = 175\text{ }^\circ\text{C}$	-	5.1	6.1	mΩ
$R_G$	gate resistance	$f = 1\text{ MHz}; T_J = 25\text{ }^\circ\text{C}$	[tbd]	0.7	[tbd]	Ω
<b>Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$I_D = 25\text{ A}; V_{DS} = 40\text{ V}; V_{GS} = 10\text{ V}$	[tbd]	83	[tbd]	nC
		$I_D = 0\text{ A}; V_{DS} = 0\text{ V}; V_{GS} = 10\text{ V}$	-	43	-	nC
$Q_{GS}$	gate-source charge	$I_D = 25\text{ A}; V_{DS} = 40\text{ V}; V_{GS} = 10\text{ V}$	[tbd]	25.2	[tbd]	nC
$Q_{GS(th)}$	pre-threshold gate-source charge		-	16.5	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	8.7	-	nC
$Q_{GD}$	gate-drain charge		[tbd]	15	[tbd]	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 25\text{ A}; V_{DS} = 40\text{ V}$	-	4.5	-	V
$C_{iss}$	input capacitance	$V_{DS} = 40\text{ V}; V_{GS} = 0\text{ V}; f = 1\text{ MHz}; T_J = 25\text{ }^\circ\text{C}$	[tbd]	6150	[tbd]	pF
$C_{oss}$	output capacitance		[tbd]	1736	[tbd]	pF
$C_{rss}$	reverse transfer capacitance		[tbd]	41	[tbd]	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 40\text{ V}; R_L = 1.6\text{ }^\Omega; V_{GS} = 10\text{ V}; R_{G(ext)} = 5\text{ }^\Omega$	-	22	-	ns
$t_r$	rise time		-	17	-	ns
$t_{d(off)}$	turn-off delay time		-	46	-	ns
$t_f$	fall time		-	24	-	ns
<b>Source-drain diode</b>						
$V_{SD}$	source-drain voltage	$I_S = 25\text{ A}; V_{GS} = 0\text{ V}; T_J = 25\text{ }^\circ\text{C}$	-	0.8	1	V
$t_{rr}$	reverse recovery time	$I_S = 25\text{ A}; di_S/dt = -100\text{ A}/\mu\text{s}; V_{GS} = 0\text{ V}; V_{DS} = 40\text{ V};$ <a href="#">Fig. 6</a>	-	33	-	ns
$Q_r$	recovered charge		-	27	-	nC

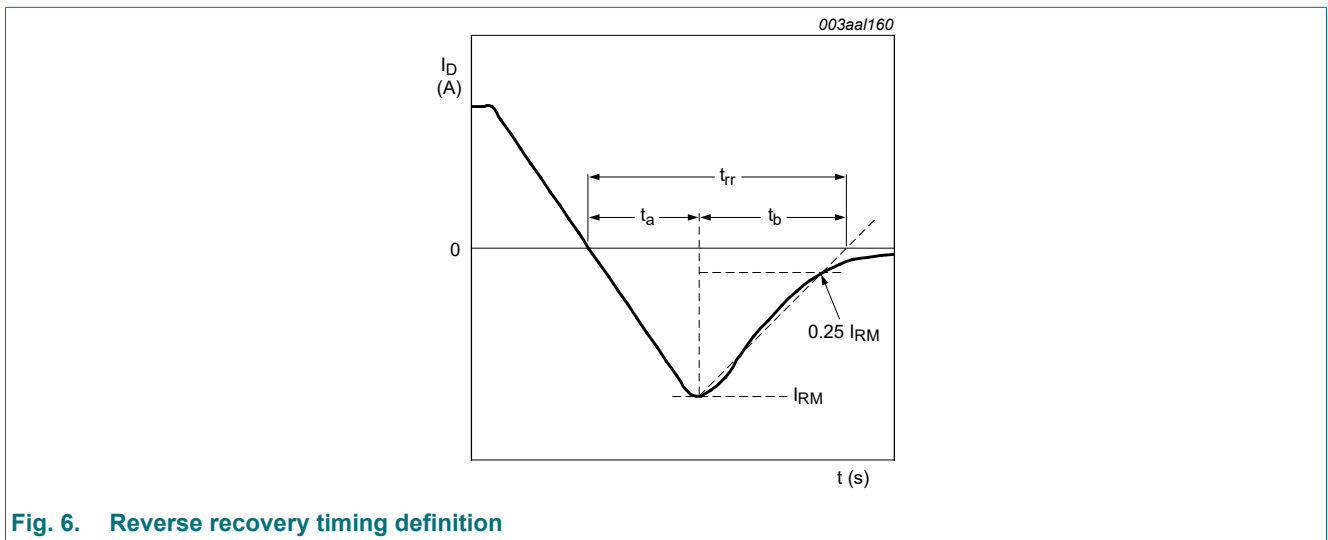


Fig. 6. Reverse recovery timing definition

10. Package outline

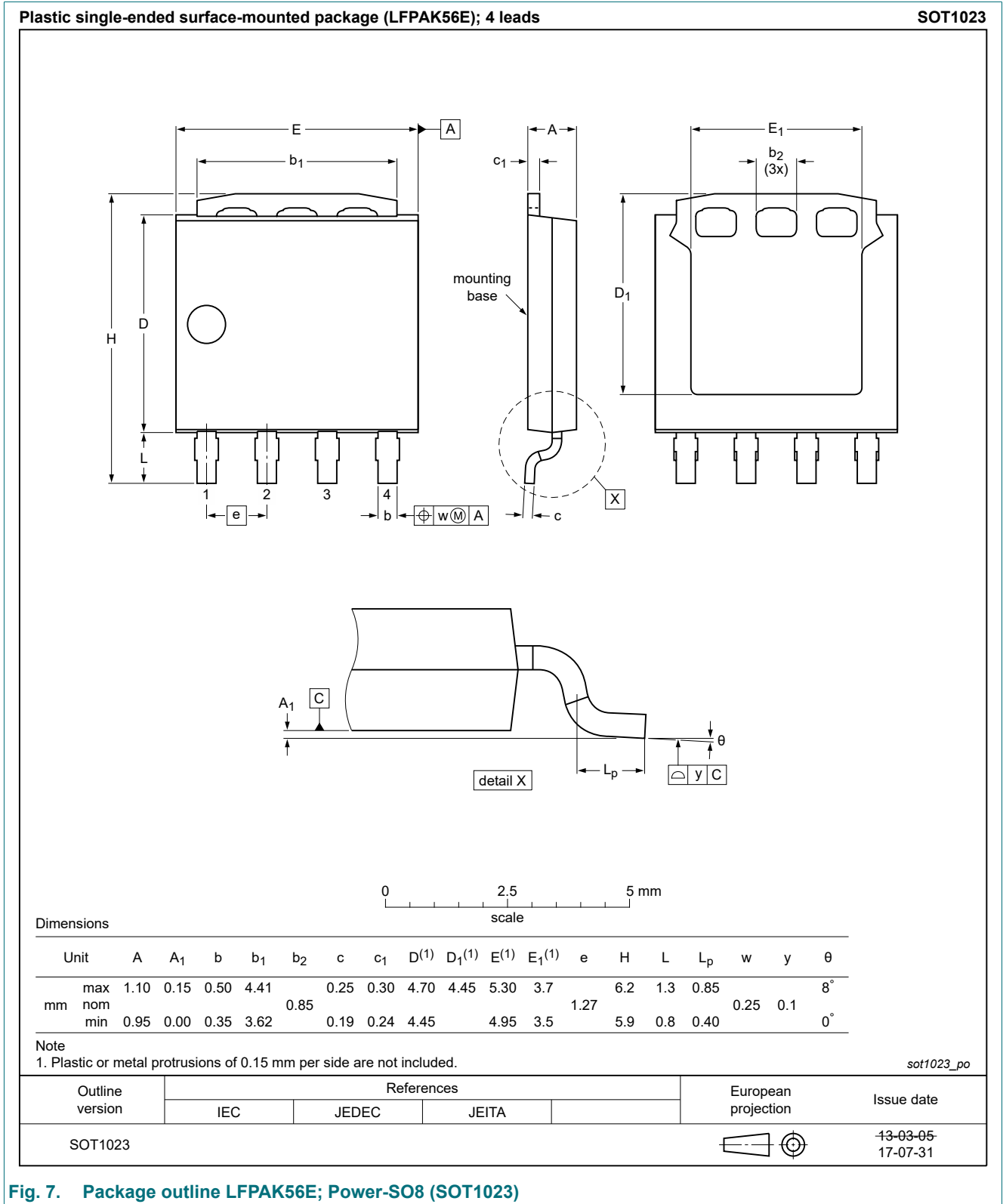


Fig. 7. Package outline LPAK56E; Power-SO8 (SOT1023)

### 11. Soldering

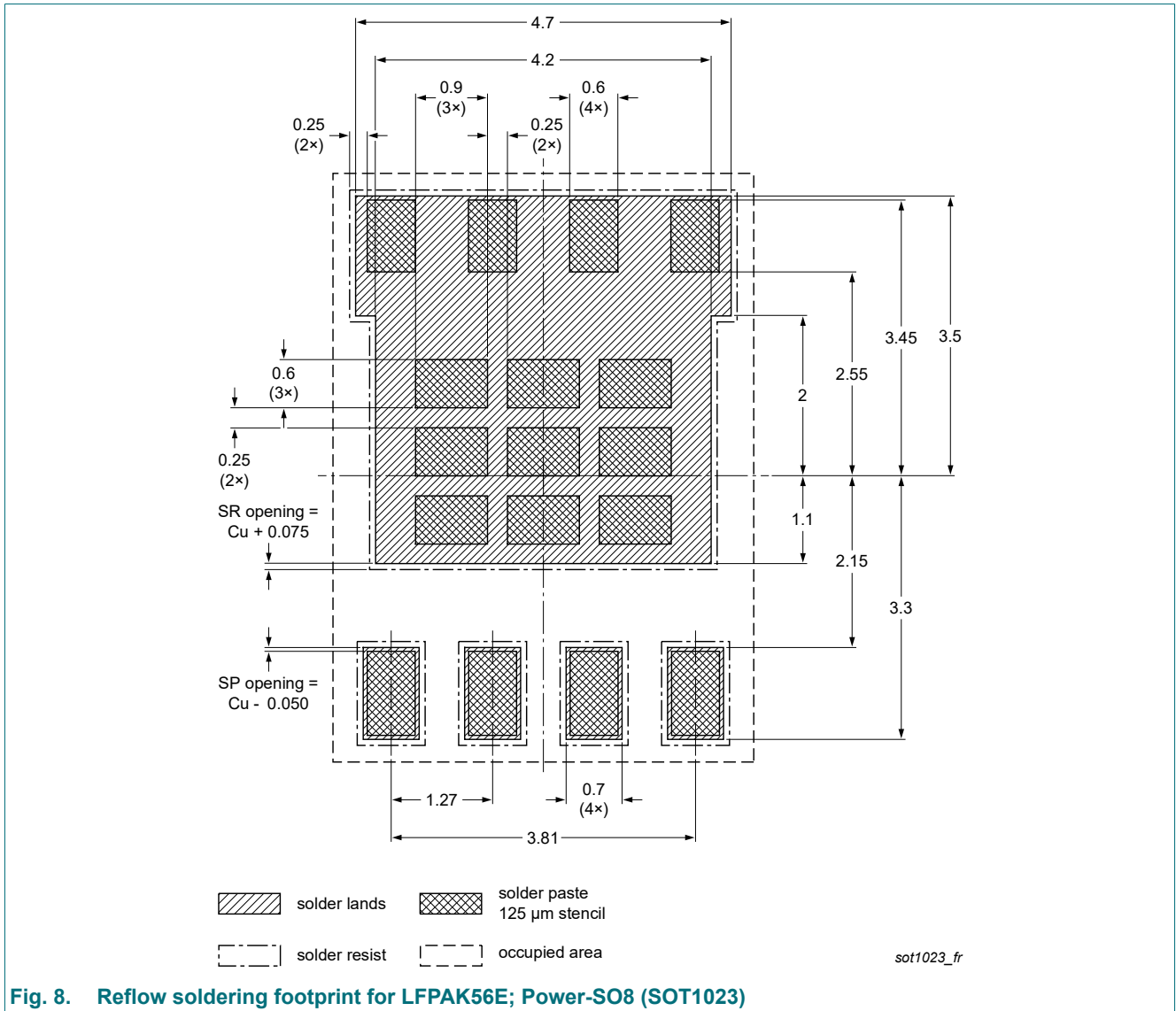


Fig. 8. Reflow soldering footprint for LPAK56E; Power-SO8 (SOT1023)

## 12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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